

## Supporting information for

# Reversible Zn-driven Reduction Displacement Reaction in Aqueous Zinc-ion Batteries

Lutong Shan,<sup>a</sup> Jiang Zhou\*,<sup>a</sup> Mingming Han,<sup>a</sup> Guozhao Fang,<sup>a</sup> Xinxin Cao,<sup>a</sup> Xianwen Wu\*,<sup>b</sup>  
and Shuquan Liang\*,<sup>a</sup>

*a School of Materials Science and Engineering, Central South University, Changsha 410083,  
P. R. China. E-mail: zhou\_jiang@csu.edu.cn, lsq@csu.edu.cn*

*b School of Chemistry and Chemical Engineering, Jishou University, Jishou 416000, P.R.  
China. E-mail: wxwcsu2011@163.com*

## 1. Experimental

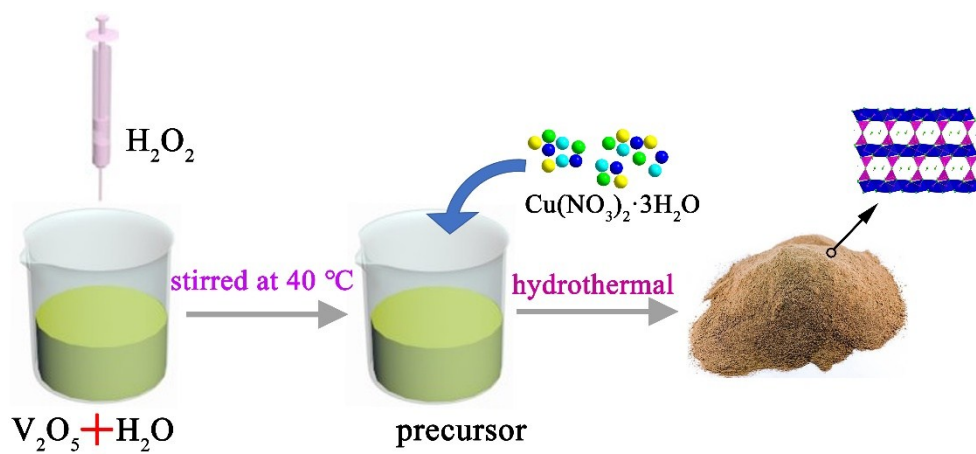
**Synthesis.** All the reactants were used as-received without further purification. Typically, 0.3 g of  $V_2O_5$  was mixed with 30 mL deionized water with 4 mL  $H_2O_2$  added dropwise. After stirred at  $40^\circ C$  for 30 min, 398.27 mg of  $Cu(NO_3)_2 \cdot 3H_2O$  was added to the above orange solution with further 30 min stirring at  $40^\circ C$ . Then the mixed solution was transferred into 50 mL Teflon-lined autoclave and heated at  $200^\circ C$  for 48 h. Finally, the  $Cu_3(OH)_2V_2O_7 \cdot 2H_2O$  nanosheet were obtained after centrifuged several times with alcohol and dried overnight.

**Material Characterization.** In our research, the X-ray power diffraction (XRD) are applied to determine the phase of the as-prepared  $Cu_3(OH)_2V_2O_7 \cdot 2H_2O$ . And Scanning electron microscopy (SEM, FEI Nova NanoSEM 230m, 10 kV) and transmission electron microscopy (TEM, Titan G2 60-300) are applied to acquire the microcosmic crystal morphologies and sizes. X-ray photoelectron spectroscopy (XPS) spectra were performed on an ESCALAB 250Xi X-ray photoelectron spectrometer (Thermo Fisher).

**Electrochemical Measurements.** In the typical synthesis, the as-prepared  $Cu_3(OH)_2V_2O_7 \cdot 2H_2O$  material were mixed with acetylene black and polyvinylidene fluoride in N-methy-2-pyrrolidone (NMP) in the weight ratio of 70:20:10 to make a slurry, which latter was used to coat the thin stainlesssteel mesh and then dried in a vacuum oven at  $80^\circ C$  for 12h. Then the coin cell assembly was executed in air condition, with the zinc metal as the anode and 3M solution of  $ZnSO_4$  as the electrolyte. The measurements of the specific capacity and rate capability was performed in Land Battery Tester (Land CT 2001A) within the voltage window of 0.4-1.4V (versus  $Zn/Zn^{2+}$ ). Besides, electrochemical workstation (MULTI AUTOLAB M204, Metrohm) was used to measure the cyclic voltammetry (CV) curves at a scan rate of 0.1

mV s<sup>-1</sup> during the voltage scale of 0.4-1.4 V (versus Zn/Zn<sup>2+</sup>) and the electrochemical impedance spectrometry (EIS) from 100 kHz to 10 mHz. Arbin instruments (S/N 170539) was applied to measure the GITT results. The loading of composites for each electrode in this experiment is about 1.2-1.6 mg with an area of 1.1304 cm<sup>2</sup>.

2.



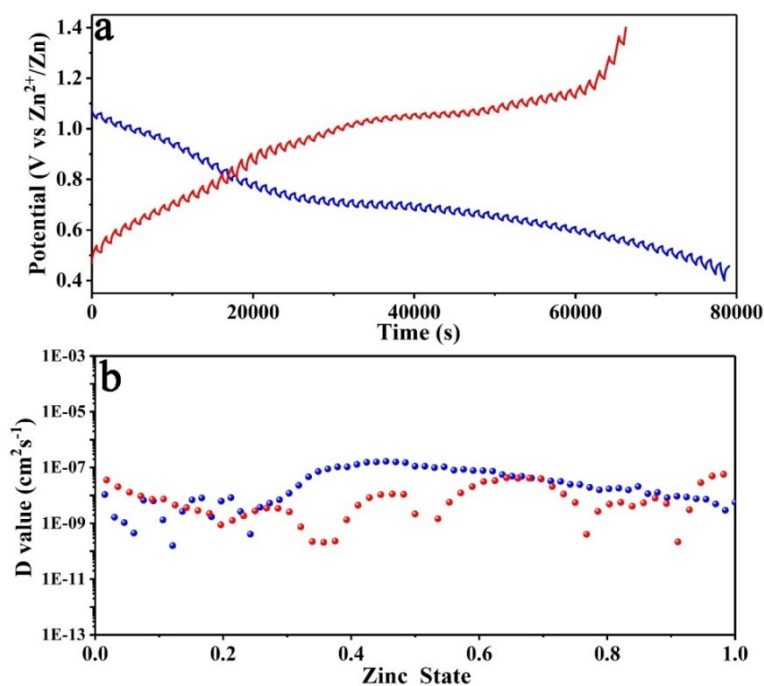
**Figure S1** Illustration of the synthesis process of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  nanosheet.

3.



**Figure S2** The successful light up of LED lamp bank with four aqueous Zn/Cu<sub>3</sub>(OH)<sub>2</sub>V<sub>2</sub>O<sub>7</sub>·2H<sub>2</sub>O coin-cells.

4.



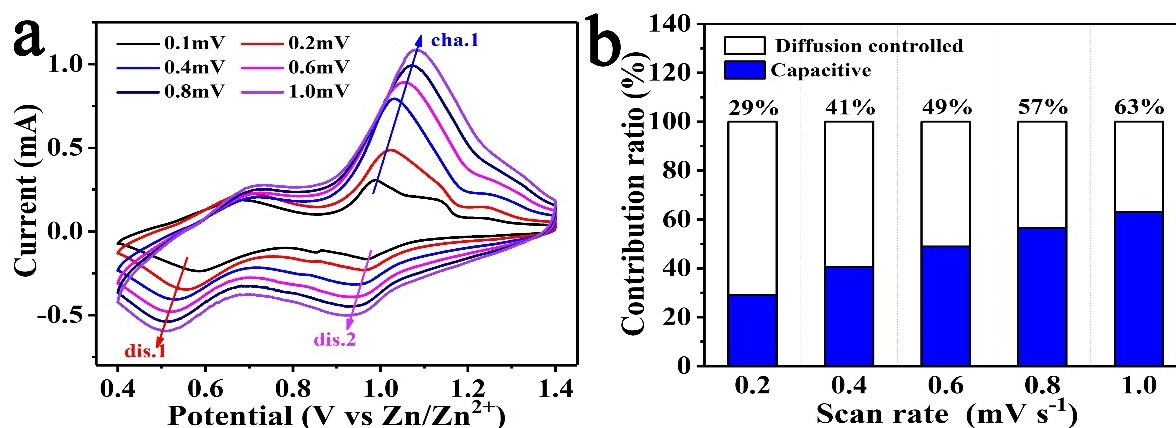
**Figure S3** (a) The discharge-charge GITT curves and (b) the zinc ion diffusion coefficient of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  material.

The diffusion coefficient of  $\text{Zn}^{2+}$  could be measured by using Galvanostatic Intermittent Titration Technique (GITT) technique and calculated via the following equation<sup>1-4</sup>:

$$D = \frac{4L^2}{\pi\tau} \left( \frac{\Delta E_s}{\Delta E_t} \right)^2$$

In the above equation,  $t$  and  $\tau$  represent the duration of current pulse (s) and relaxation time (s), respectively.  $L$  corresponds to  $\text{Zn}^{2+}$  diffusion length, which is equal to thickness of electrode.  $\Delta E_s$  and  $\Delta E_t$  are the steady-state voltage change (V) by the current pulse and voltage change (V) during the constant current pulse (eliminating the voltage changes after relaxation time).

5.



**Figure S4** (a) CV curves at various scan rates of 0.1-1.0 mV s<sup>-1</sup>, (b) Contribution ratios comparison of capacitive effect and diffusion process at various scan rates.

As elucidated,<sup>5</sup> the kinetic of capacitive contribution can be obtained through calculating the CV curves at different scan rates. It is ought to be noted that there is a power law that links the scan rate with the current, which is:  $i=av^b$ . Here, the equation can be converted as:  $\log(i)=\log(a)+b*\log(v)$ , henceforth, by calculating the value of  $\log(i)$  and  $\log(v)$ , we can reach a precise  $b$  value via a consequent mathematical fitting. As known, if the value of  $b$  is 0.5, we can summarize that the capacity is fully contributed by diffusion process, while the  $b$  value is 1, we can conclude that the capacity is ruled by the capacitive effect.

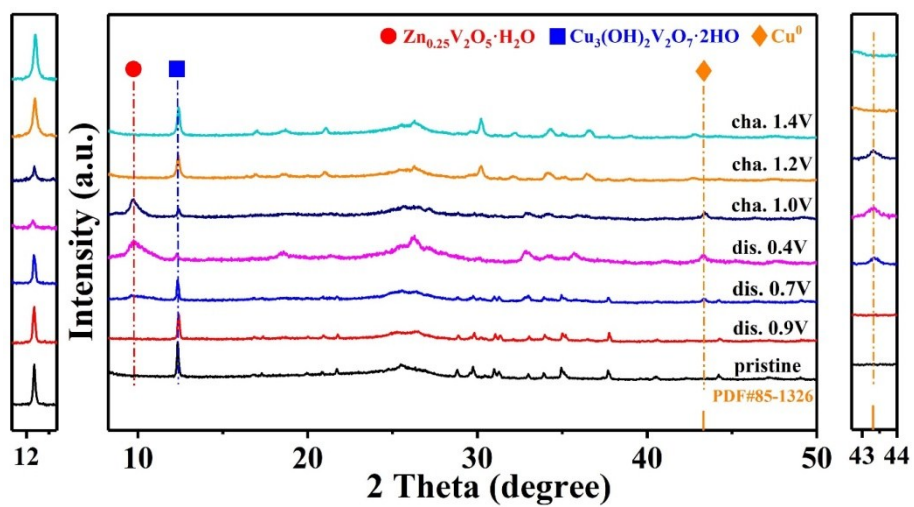
Furthermore, there is an equation that matches the two factors of diffusion-controlled contribution and the capacitive effects with the current, which is:  $i=k_1v^{1/2}+k_2v$ .

In this formula, when the  $k_1$  value reaches for 0, then it turns to be:  $i=k_2v$ , which is similar to  $i=av$ , and we can reasonably speculate that the capacity is mainly ascribed to capacitive effect. The same way, when the  $k_2$  value is close to 0.5, which makes the equation agree well with  $i=av^{0.5}$ , then it can be deduced that diffusion-controlled process mostly account for

capacity, typically. As shown in **Fig. S4b**, with the increasing scan rates, the capacitive contribution ratio emerges an increasing trend.

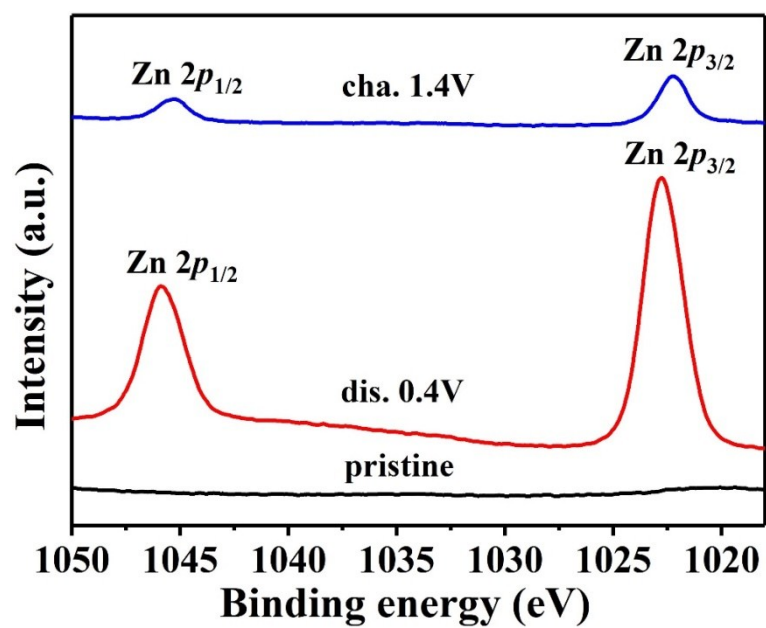


6.



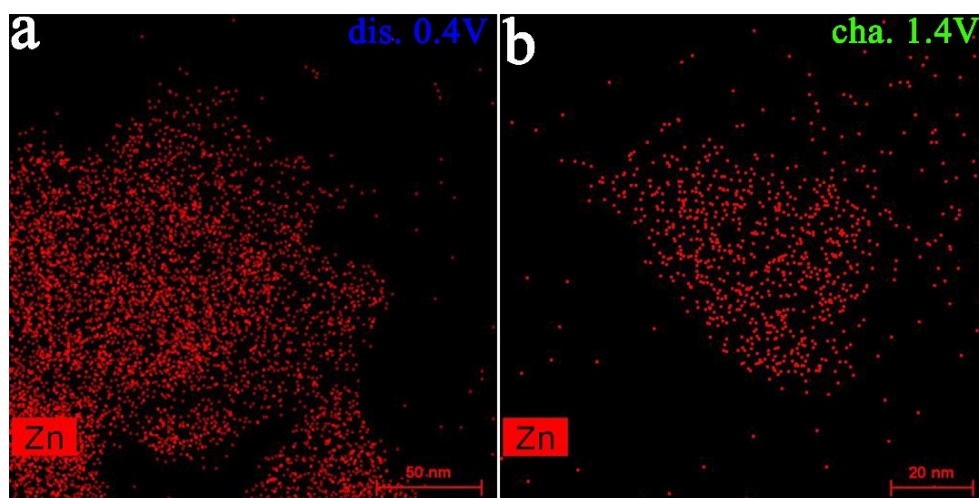
**Figure S5** *Ex-situ* XRD measurements at different discharge-charge states of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  material with carbon cloth as current collector.

7.



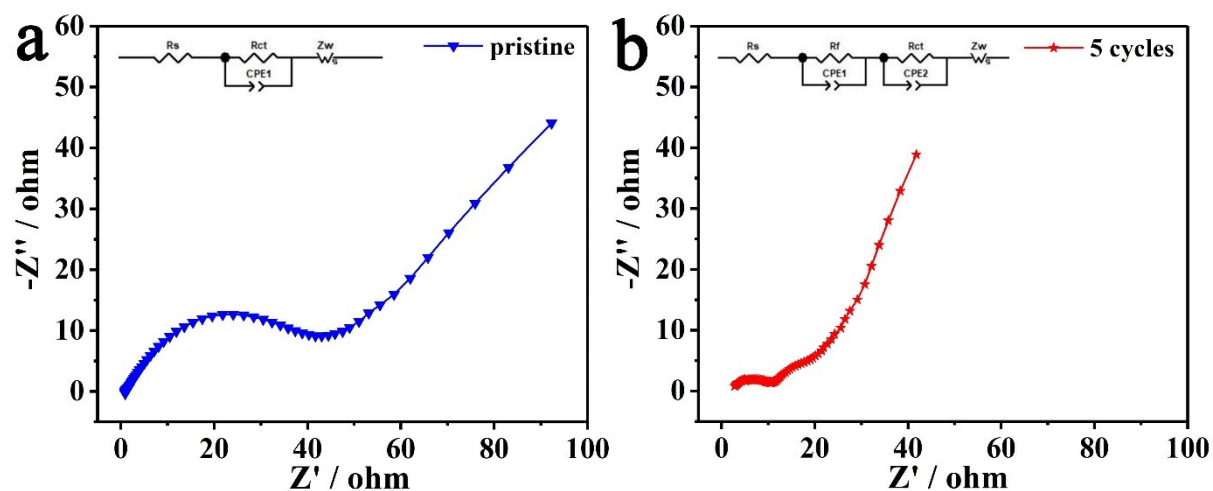
**Figure S6** The Zn 2p spectra at various states of pristine, completely discharged and completely charged.

8.



**Figure S7**  $\text{Zn}^{2+}$  ions EDS element mapping of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  product at (a) fully discharged and (b) fully charged state.

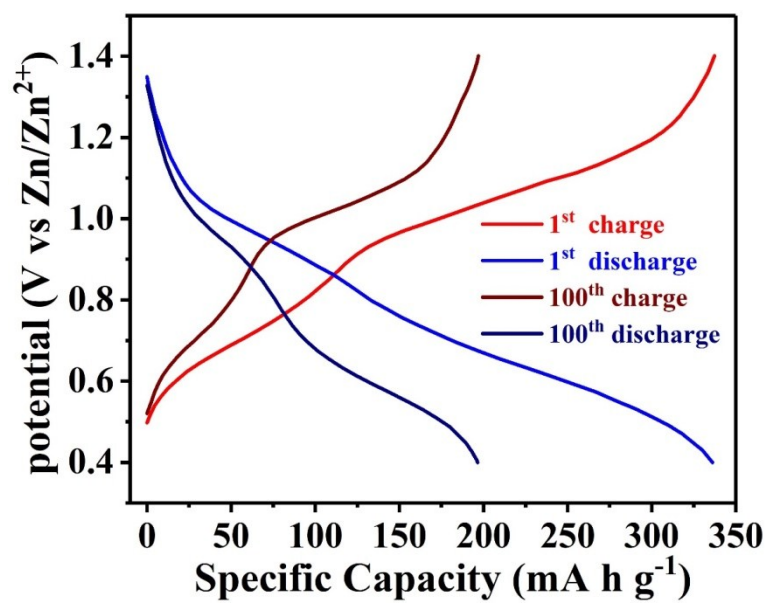
9.



**Figure S8** The EIS results and correspond equivalent electrical circuits of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  cathode at (a) pristine state and (b) after 5 cycles.

$R_s$  represents the electrolyte resistance,  $R_f$  suggests the resistance of SEI layer and  $R_{ct}$  represents the charge-transfer resistance. In **Fig. S8**, the EIS results and correspond equivalent electrical circuits indicate that SEI layer does not exist at pristine state and appears after 5 galvanostatic discharge-charge cycles, contributing to the resistance ( $R_f$ ). The primary EIS simulation parameters can be seen in **Table S1**. After 5 cycles,  $R_s$  remains stable, and  $R_{ct}$  manifests significant decrease from 41.02  $\Omega$  to 20.83  $\Omega$ , which could be attributed to the formation of metallic  $\text{Cu}^0$  upon discharge as well as the activation process.<sup>6, 7</sup>

10.



**Figure S9** The discharge-charge profiles at 1<sup>st</sup> and 100<sup>th</sup> cycle of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  at 1 A g<sup>-1</sup>.

**11. Table S1** The Primary EIS Simulation Parameters of  $\text{Cu}_3(\text{OH})_2\text{V}_2\text{O}_7 \cdot 2\text{H}_2\text{O}$  electrodes

<b>Samples</b>	<b><math>R_s</math> (<math>\Omega</math>)</b>	<b><math>R_f</math> (<math>\Omega</math>)</b>	<b><math>R_{ct}</math> (<math>\Omega</math>)</b>
<b>pristine</b>	<b>6.178</b>	<b>-</b>	<b>41.02</b>
<b>5 cycles</b>	<b>5.714</b>	<b>3.252</b>	<b>20.83</b>

## Reference

1. A. K. Jordan Anderson, Diego J. Díaz and Sudipta Seal, *J. Phys. Chem. C*, 2010, **114**, 4595–4602.
2. B. A. B. a. R. A. H. C. JohnWen, *J. Electrochem. Soc.*, 1979, **126**, 2258-2266.
3. W. W. a. R. A. Huggins, *J. Electrochem. Soc.*, 1977, **124**, 1569-1577.
4. D. T. Ngo, H. T. T. Le, C. Kim, J.-Y. Lee, J. G. Fisher, I.-D. Kim and C.-J. Park, *Energy Environ. Sci.*, 2015, **8**, 3577-3588.
5. W. Wen, J.-M. Wu, Y.-Z. Jiang, L.-L. Lai and J. Song, *Chem*, 2017, **2**, 404-416.
6. W. Ren, H. Zhang, C. Guan and C. Cheng, *Adv. Funct. Mater.*, 2017, **27**, 1702116.
7. J. Xu, M. Wang, N. P. Wickramaratne, M. Jaroniec, S. Dou and L. Dai, *Adv. Mater.*, 2015, **27**, 2042-2048.